

**AMENDMENTS TO THE CLAIMS**

1. (Currently Amended) A liquid crystal display (LCD) device, comprising:

a thin film transistor (TFT) formed on a substrate, the TFT having a gate, a source and a drain;

a color filter layer on the TFT, and in direct contact with the source and the drain, wherein said contact is only at a portion where said color filter layer is overlapping only edge portions of the source and drain so as to prevent light leakage and improve an aperture ratio; and

a pixel electrode formed above the color filter layer to be in electrical contact with the drain.

2. (Previously Presented) The device of claim 1, wherein the color filter layer and e drain are in direct contact such that there are no intermediaries therebetween.

3. (Previously Presented) A method of manufacturing a liquid crystal display (LCD) device, comprising:

forming a thin film transistor (TFT) on a substrate, the TFT having a gate, a source and a drain;

forming a color filter layer on the TFT, in direct electrical contact with the source and the drain, wherein said electrical contact is only at a portion where said color filter layer is overlapping only edge portions of the source and drain so as to prevent light leakage and improve an aperture ratio; and

forming a pixel electrode above the color filter layer to be in electrical contact with the drain.

4. (Previously Presented) The method according to claim 3, wherein the LCD is manufactured without forming a passivation layer between the TFT and the color filter layer.